

02/09/98



SHEET 1 OF 2

FORM PTO-1449 (SUBSTITUTE) U.S. DEPARTMENT OF COMMERCE PATENT AND TRADEMARK OFFICE INFORMATION DISCLOSURE STATEMENT BY APPLICANT (37 CFR 1.98(b))	Attorney Docket No.: GR 95 P 1411	Serial No. <i>02 020872</i>
	Applicant GUNTHER PLASA	
	Filing Date FEBRUARY 9, 1998	Group Art Unit

EXAMINER INITIALS		PATENT NO.	DATE	PATENTEE	CLASS	SUB CLASS	FILING DATE
<i>WZ</i>	A	5,109,258	04/92	Redwine	<i>---</i>	<i>---</i>	
<i>WZ</i>	B	4,400,867	08/83	Fraser	<i>---</i>	<i>---</i>	
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FOREIGN PATENT DOCUMENT

		DOCUMENT NO.	DATE	COUNTRY	CLASS	SUB CLASS	TRANSL. YES NO
<i>WZ</i>	J	2739662	03/79	Germany	<i>---</i>	<i>---</i>	X
<i>WZ</i>	K	2520047	12/75	Germany	<i>---</i>	<i>---</i>	X
<i>WZ</i>	L	0294699A2	12/88	Europe	<i>---</i>	<i>---</i>	X
<i>WZ</i>	M	57-42169	03/82	Japan	<i>---</i>	<i>---</i>	X
	N						

OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, etc.)

<i>WZ</i>	IEEE Transactions on Electron Devices, October 1984, Volume ED-31, Number 10
<i>WZ</i>	Japanese Patent Abstract No. 61-248532 (Mitsui), dated November 5, 1986

EXAMINER <i>Walt J. Zink</i>	DATE CONSIDERED <i>9/27/99</i>
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EXAMINER: Initial if citation considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

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<i>WZ</i>		IEEE Transactions on Electron Devices, January 1981, Volume ED-28, Number 1
<i>WZ</i>		"Formation of High Quality Storage Capacitor Dielectrics by in-situ Rapid Thermal Reoxidation of Si ₃ N ₄ Films in N ₂ O Ambient", IEEE Electron Device Letters, Vol. 15, No. 8, August 1994, pp. 266-268
EXAMINER <i>Michael L. Lachman</i>		DATE CONSIDERED <i>9/27/99</i>
EXAMINER: Initial if citation considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.		